

LM10

Operational Amplifier and Voltage Reference

General Description

The LM10 series are monolithic linear ICs consisting of a precision reference, an adjustable reference buffer and an independent, high quality op amp.

The unit can operate from a total supply voltage as low as 1.1V or as high as 40V, drawing only $270\mu A$. A complementary output stage swings within 15 mV of the supply terminals or will deliver ± 20 mA output current with ± 0.4 V saturation. Reference output can be as low as 200 mV.

The circuit is recommended for portable equipment and is completely specified for operation from a single power cell. In contrast, high output-drive capability, both voltage and current, along with thermal overload protection, suggest it in demanding general-purpose applications.

The device is capable of operating in a floating mode, independent of fixed supplies. It can function as a remote comparator, signal conditioner, SCR controller or transmitter for

analog signals, delivering the processed signal on the same line used to supply power. It is also suited for operation in a wide range of voltage- and current-regulator applications, from low voltages to several hundred volts, providing greater precision than existing ICs.

This series is available in the three standard temperature ranges, with the commercial part having relaxed limits. In addition, a low-voltage specification (suffix "L") is available in the limited temperature ranges at a cost savings.

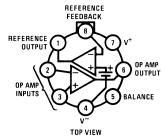
Features

input offset voltage: 2.0 mV (max)
 input offset current: 0.7 nA (max)
 input bias current: 20 nA (max)
 reference regulation: 0.1% (max)
 offset voltage drift: 2µV/°C

■ reference drift: 0.002%/°C

Connection and Functional Diagrams

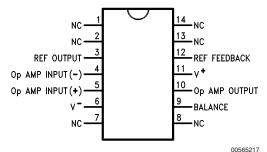
Metal Can Package (H)



00565201

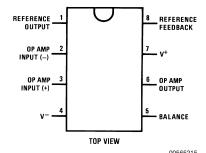
Order Number LM10BH, LM10CH, LM10CLH or LM10H/883 available per SMA# 5962-8760401 See NS Package Number H08A

Small Outline Package (WM)

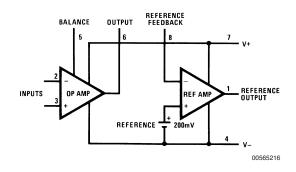


Order Number LM10CWM or LM10CWMX See NS Package Number M14B

Dual-In-Line Package (N)



Order Number LM10CN or LM10CLN See NS Package Number N08E



Absolute Maximum Ratings (Notes 1,

8)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

LM10/LM10B/LM10BL/							
LM10C	LM10CL						

Total Supply Voltage 45V 7V

Differential Input Voltage (Note 2) ±40V ±7V

Power Dissipation (Note 3) internally limited

Output Short-circuit Duration (Note continuous

4)

Storage-Temp. Range -55°C to +150°C

Lead Temp. (Soldering, 10 seconds)

Metal Can 300°C Lead Temp. (Soldering, 10 260°C

seconds) DIP

Vapor Phase (60 seconds) 215°C Infrared (15 seconds) 220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

ESD rating is to be determined.

Maximum Junction Temperature

 LM10
 150°C

 LM10B
 100°C

 LM10C
 85°C

Operating Ratings

Package Thermal Resistance

 θ_{JA}

H Package 150°C/W
N Package 87°C/W
WM Package 90°C/W

 θ_{10}

H Package 45°C/W

Electrical Characteristics

 $T_J=25$ °C, $T_{MIN} \le T_J \le T_{MAX}$ (Boldface type refers to limits over temperature range) (Note 5)

Parameter	Conditions	LM10/LM10B			LM10C			Units
		Min	Тур	Max	Min	Тур	Max	1
Input offset voltage			0.3	2.0		0.5	4.0	mV
				3.0			5.0	mV
Input offset current			0.25	0.7		0.4	2.0	nA
(Note 6)				1.5			3.0	nA
Input bias current			10	20		12	30	nA
				30			40	nA
Input resistance		250	500		150	400		kΩ
		150			115			kΩ
Large signal voltage	V _S =±20V, I _{OUT} =0	120	400		80	400		V/mV
gain	V _{OUT} =±19.95V	80			50			V/mV
	$V_S=\pm 20V$, $V_{OUT}=\pm 19.4V$	50	130		25	130		V/mV
	I _{OUT} =±20 mA (±15 mA)	20			15			V/mV
	V _S =±0.6V (0.65V), I _{OUT} =±2 mA	1.5	3.0		1.0	3.0		V/mV
	V _{OUT} =±0.4V (±0.3V), V _{CM} =-0.4V	0.5			0.75			V/mV
Shunt gain (Note 7)	1.2V (1.3V) ≤V _{OUT} ≤40V,	14	33		10	33		V/mV
	$R_L=1.1 \text{ k}\Omega$							
	0.1 mA≤I _{OUT} ≤5 mA	6			6			V/mV
	1.5V≤V ⁺ ≤40V, R _L =250Ω	8	25		6	25		V/mV
	0.1 mA≤l _{OUT} ≤20 mA	4			4			V/mV
Common-mode	-20V≤V _{CM} ≤19.15V (19V)	93	102		90	102		dB
rejection	V _S =±20V	87			87			dB
Supply-voltage	-0.2V≥V⁻≥-39V	90	96		87	96		dB
rejection	V ⁺ =1.0V (1.1V)	84			84			dB
	1.0V (1.1V) ≤V+≤39.8V	96	106		93	106		dB
	V ⁻ =-0.2V	90			90			dB
Offset voltage drift			2.0			5.0		μV/°C
Offset current drift			2.0			5.0		pA/°C
Bias current drift	T _C <100°C		60			90		pA/°C

Electrical Characteristics (Continued)

 $T_J=25^{\circ}C$, $T_{MIN}\le T_J\le T_{MAX}$ (Boldface type refers to limits over temperature range) (Note 5)

Parameter	Conditions	LM10/LM10B			LM10C			Units
		Min	Тур	Max	Min	Тур	Max	
Line regulation	1.2V (1.3V) ≤V _S ≤40V		0.001	0.003		0.001	0.008	%/V
	0≤I _{REF} ≤1.0 mA, V _{REF} =200 mV			0.006			0.01	%/V
Load regulation	0≤I _{REF} ≤1.0 mA		0.01	0.1		0.01	0.15	%
	V ⁺ –V _{REF} ≥1.0V (1.1V)			0.15			0.2	%
Amplifier gain	0.2V≤V _{REF} ≤35V	50	75		25	70		V/mV
		23			15			V/mV
Feedback sense		195	200	205	190	200	210	mV
voltage		194		206	189		211	mV
Feedback current			20	50		22	75	nA
				65			90	nA
Reference drift			0.002			0.003		%/°C
Supply current			270	400		300	500	μA
				500			570	μΑ
Supply current	1.2V (1.3V) ≤V _S ≤40V		15	75		15	75	μΑ
change								

Electrical Characteristics

 $T_J=25^{\circ}C$, $T_{MIN} \le T_J \le T_{MAX}$ (Boldface type refers to limits over temperature range) (Note 5)

Parameter	Conditions	LM10BL			LM10CL			Units
		Min	Тур	Max	Min	Тур	Max	1
Input offset voltage			0.3	2.0		0.5	4.0	mV
				3.0			5.0	mV
Input offset current			0.1	0.7		0.2	2.0	nA
(Note 6)				1.5			3.0	nA
Input bias current			10	20		12	30	nA
				30			40	nA
Input resistance		250	500		150	400		kΩ
		150			115			kΩ
Large signal voltage	V _S =±3.25V, I _{OUT} =0	60	300		40	300		V/mV
gain	V _{OUT} =±3.2V	40			25			V/mV
	$V_S=\pm 3.25V$, $I_{OUT}=10$ mA	10	25		5	25		V/mV
	V _{OUT} =±2.75 V	4			3			V/mV
	$V_S = \pm 0.6V$ (0.65V), $I_{OUT} = \pm 2$ mA	1.5	3.0		1.0	3.0		V/mV
	$V_{OUT} = \pm 0.4 V$ (±0.3V), $V_{CM} = -0.4 V$	0.5			0.75			V/mV
Shunt gain (Note 7)	1.5V≤V ⁺ ≤6.5V, R _L =500Ω	8	30		6	30		V/mV
	0.1 mA≤l _{OUT} ≤10 mA	4			4			V/mV
Common-mode	-3.25V≤V _{CM} ≤2.4V (2.25V)	89	102		80	102		dB
rejection	V _S =±3.25V	83			74			dB
Supply-voltage	-0.2V≥V⁻≥-5.4V	86	96		80	96		dB
rejection	V ⁺ =1.0V (1.2V)	80			74			dB
	1.0V (1.1V) ≤V ⁺ ≤6.3V	94	106		80	106		dB
	V ⁻ =0.2V	88			74			dB
Offset voltage drift			2.0			5.0		μV/°C
Offset current drift			2.0			5.0		pA/°C
Bias current drift			60			90		pA/°C
Line regulation	1.2V (1.3V) ≤V _S ≤6.5V		0.001	0.01		0.001	0.02	%/V
	0≤I _{REF} ≤0.5 mA, V _{REF} =200 mV			0.02			0.03	%/V

Electrical Characteristics (Continued)

 $T_J=25^{\circ}C$, $T_{MIN} \le T_J \le T_{MAX}$ (Boldface type refers to limits over temperature range) (Note 5)

Parameter	Conditions		LM10BL LM10CL				Units	
		Min	Тур	Max	Min	Тур	Max	
Load regulation	0≤I _{REF} ≤0.5 mA		0.01	0.1		0.01	0.15	%
	V ⁺ –V _{REF} ≥1.0V (1.1V)			0.15			0.2	%
Amplifier gain	0.2V≤V _{REF} ≤5.5V	30	70		20	70		V/mV
		20			15			V/mV
Feedback sense voltage		195	200	205	190	200	210	mV
		194		206	189		211	mV
Feedback current			20	50		22	75	nA
				65			90	nA
Reference drift			0.002			0.003		%/°C
Supply current			260	400		280	500	μΑ
				500			570	μΑ

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Note 2: The Input voltage can exceed the supply voltages provided that the voltage from the input to any other terminal does not exceed the maximum differential input voltage and excess dissipation is accounted for when $V_{IN} < V^-$.

Note 3: The maximum, operating-junction temperature is 150°C for the LM10, 100°C for the LM10B(L) and 85°C for the LM10C(L). At elevated temperatures, devices must be derated based on package thermal resistance.

Note 4: Internal thermal limiting prevents excessive heating that could result in sudden failure, but the IC can be subjected to accelerated stress with a shorted output and worst-case conditions.

Note 5: These specifications apply for $V^- \le V_{CM} \le V^+ - 0.85V$ (1.0V), 1.2V (1.3V) $< V_S \le V_{MAX}$, $V_{REF} = 0.2V$ and $0 \le I_{REF} \le 1.0$ mA, unless otherwise specified: $V_{MAX} = 40V$ for the standard part and 6.5V for the low voltage part. Normal typeface indicates 25°C limits. **Boldface type indicates limits and altered test conditions for full-temperature-range operation**; this is -55° C to 125° C for the LM10, -25° C for the LM10B(L) and 0° C to 70° C for the LM10C(L). The specifications do not include the effects of thermal gradients ($\tau_1 = 20$ ms), die heating ($\tau_2 = 0.2s$) or package heating. Gradient effects are small and tend to offset the electrical error (see curves).

Note 6: For $T_J > 90^{\circ}C$, I_{OS} may exceed 1.5 nA for $V_{CM} = V^{-}$. With $T_J = 125^{\circ}C$ and $V^{-} \le V_{CM} \le V^{-} + 0.1V$, $I_{OS} \le 5$ nA.

Note 7: This defines operation in floating applications such as the bootstrapped regulator or two-wire transmitter. Output is connected to the V⁺ terminal of the IC and input common mode is referred to V⁻ (see typical applications). Effect of larger output-voltage swings with higher load resistance can be accounted for by adding the positive-supply rejection error.

Note 8: Refer to RETS10X for LM10H military specifications.

Definition of Terms

Input offset voltage: That voltage which must be applied between the input terminals to bias the unloaded output in the linear region.

Input offset current: The difference in the currents at the input terminals when the unloaded output is in the linear region.

Input bias current: The absolute value of the average of the two input currents.

Input resistance: The ratio of the change in input voltage to the change in input current on either input with the other grounded. Large signal voltage gain: The ratio of the specified output voltage swing to the change in differential input voltage required to

Shunt gain: The ratio of the specified output voltage swing to the change in differential input voltage required to produce it with the output tied to the V⁺ terminal of the IC. The load and power source are connected between the V⁺ and V⁻ terminals, and input common-mode is referred to the V⁻ terminal.

Common-mode rejection: The ratio of the input voltage range to the change in offset voltage between the extremes.

Supply-voltage rejection: The ratio of the specified supply-voltage change to the change in offset voltage between the extremes.

Line regulation: The average change in reference output voltage over the specified supply voltage range.

Load regulation: The change in reference output voltage from no load to that load specified.

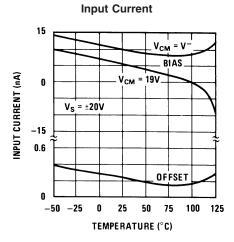
Feedback sense voltage: The voltage, referred to V-, on the reference feedback terminal while operating in regulation.

Reference amplifier gain: The ratio of the specified reference output change to the change in feedback sense voltage required to produce it.

Feedback current: The absolute value of the current at the feedback terminal when operating in regulation.

Supply current: The current required from the power source to operate the amplifier and reference with their outputs unloaded and operating in the linear range.

Typical Performance Characteristics (Op Amp)



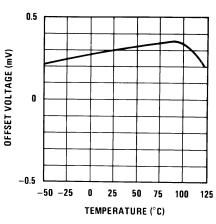
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0 -0.5COMMON-MODE LIMITS (V) -1.0 $\Delta V_{OS} < 0.1 \ mV$ $\Delta I_{OS} < 0.2 \text{ nA}$ 0 < 1 nA $\overline{\Delta V_{OS}} < 0.5 \text{ mV}$ -0.5OS < 2 nA اکا OS < 2 nA اکا B < 10 nA -1.0-50 -25 25 50 75 TEMPERATURE (°C)

Common Mode Limits

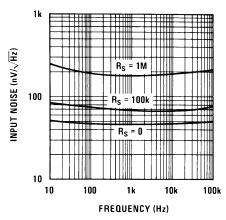
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Output Voltage Drift



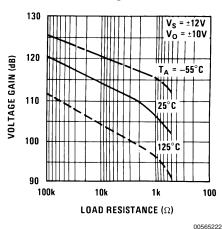
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Input Noise Voltage

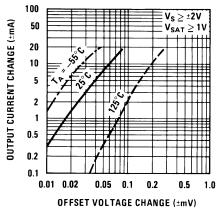


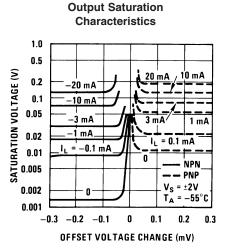
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DC Voltage Gain



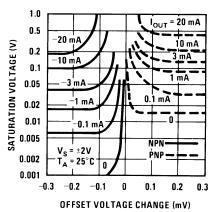
Transconductance





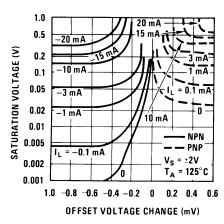
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Output Saturation Characteristics



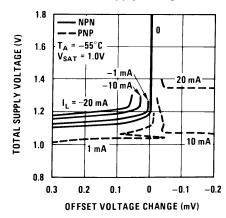
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Output Saturation Characteristics



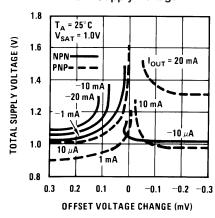
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Minimum Supply Voltage



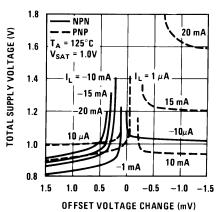
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Minimum Supply Voltage

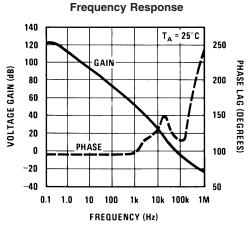


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Minimum Supply Voltage



00565229

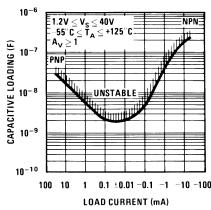


00565230

1k OUTPUT IMPEDANCE (12) 100 10 0.1 100k 1M FREQUENCY (Hz) 00565231

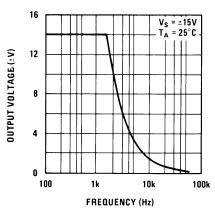
Output Impedance

Typical Stability Range

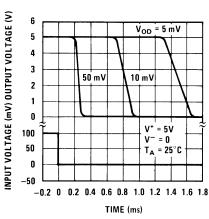


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Large Signal Response



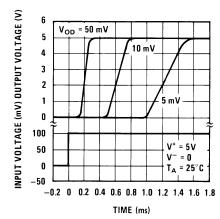
Comparator Response Time For Various Input Overdrives

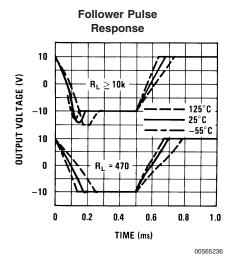


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Comparator Response Time For Various Input Overdrives





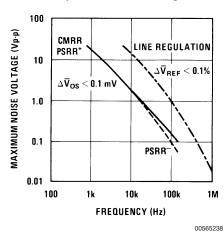
140 V_{REF} = 200 mV 120 PSRR* NOISE REJECTION (48) LINE 100 REGULATION CMRR 80 60 PSRR 40 20 10 100 1k 100k

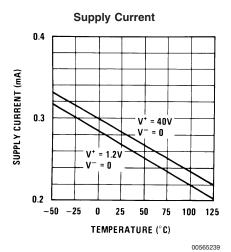
FREQUENCY (Hz)

Noise Rejection

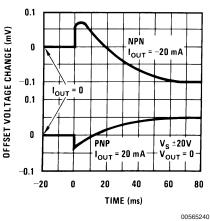
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Rejection Slew Limiting



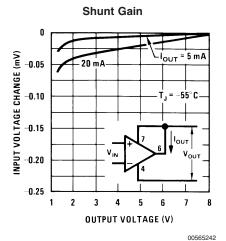


Thermal Gradient Feedback 0.1

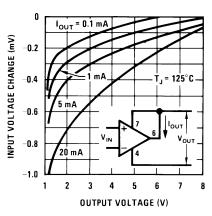


Cross-coupling 0.05 REFERENCE VOLTAGE CHANGE (%) NPN I_{OUT} = -20 mA 0.05 I_{OUT} = 0 PNP 0.05 I_{OUT} = 20 mA V_S ±20V V_{OUT} = 0 -0.05 -20 0 80 20 40 60 TIME (ms)

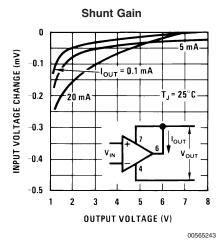
Thermal Gradient



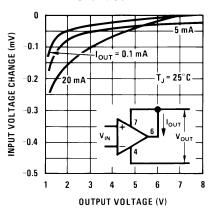
Shunt Gain



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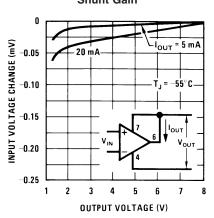


Shunt Gain



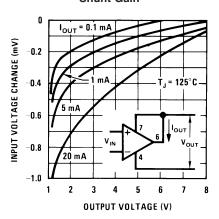
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Shunt Gain

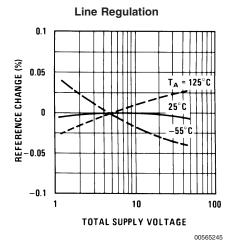


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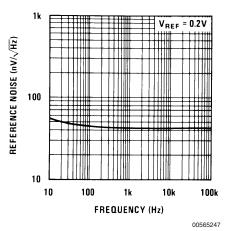
Shunt Gain



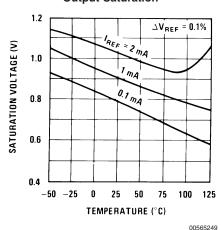
Typical Performance Characteristics (Reference)



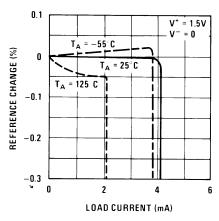
Reference Noise Voltage



Output Saturation

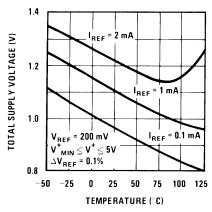


Load Regulation



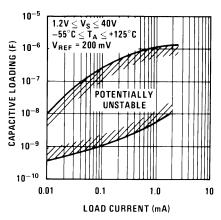
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Minimum Supply Voltage



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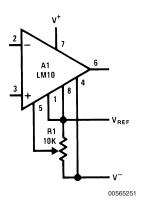
Typical Stability Range



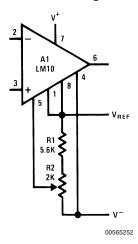
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Op Amp Offset Adjustment

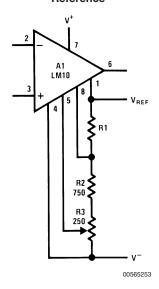
Standard



Limited Range

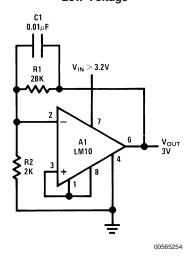


Limited Range With Boosted Reference

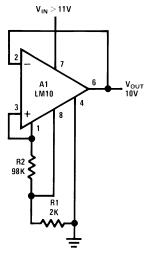


Positive Regulators (Note 9)

Low Voltage

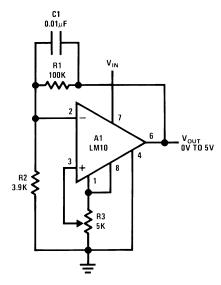


Best Regulation



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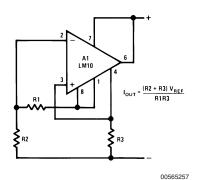
Zero Output



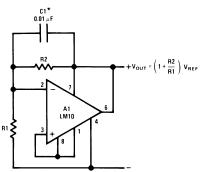
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Note 9: Use only electrolytic output capacitors.

Current Regulator



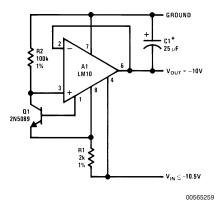
Shunt Regulator



Required For Capacitive Loading

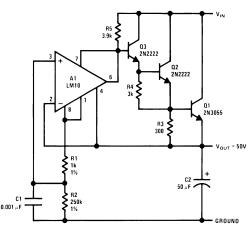
00565258

Negative Regulator

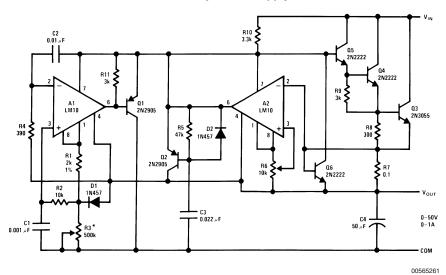


*Electrolytic

Precision Regulator

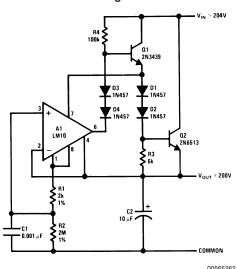


Laboratory Power Supply



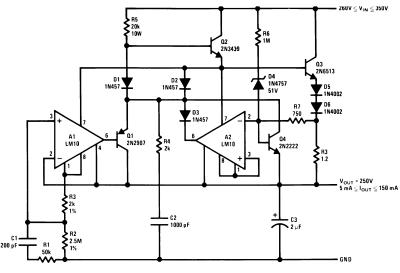
*V_{OUT}=10⁻⁴ R3

HV Regulator



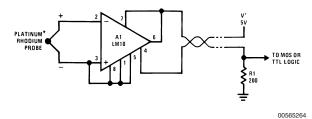
 $V_{OUT} = \frac{R2}{R1} V_{REF}$

Protected HV Regulator



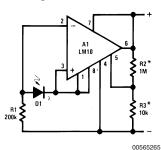
00565263

Flame Detector



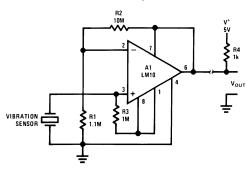
 $^{*}800^{\circ}\text{C}$ Threshold Is Established By Connecting Balance To $\text{V}_{\text{REF}}.$

Light Level Sensor



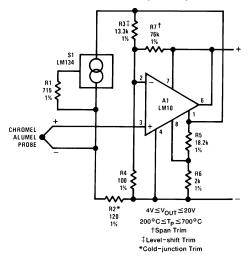
*Provides Hysteresis

Remote Amplifier



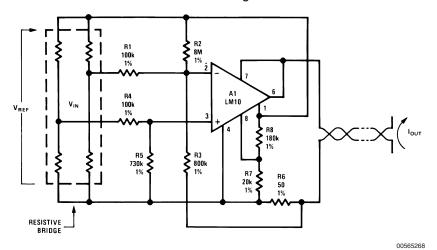
00565266

Remote Thermocouple Amplifier

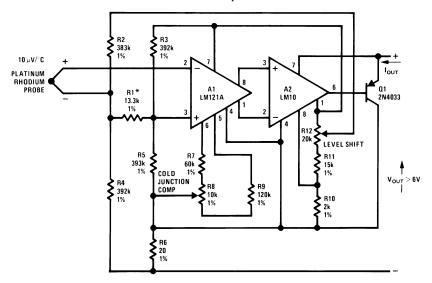


00565267

Transmitter for Bridge Sensor

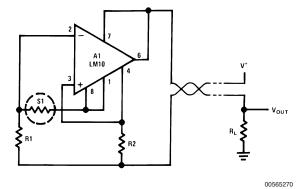


Precision Thermocouple Transmitter



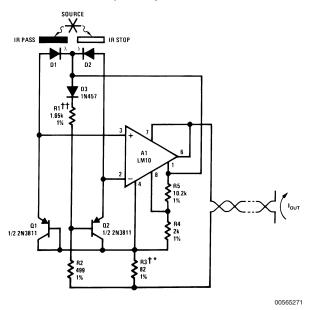
10 mA \leq l $_{OUT}\leq$ 50 mA 500°C \leq T $_{P}\leq$ 1500°C *Gain Trim

Resistance Thermometer Transmitter



16

Optical Pyrometer



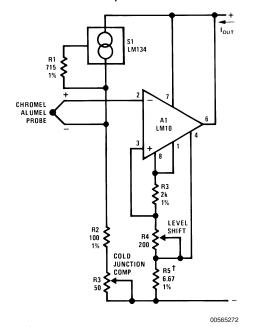
††Level-shift Trim

*Scale Factor Trim

†Copper Wire Wound

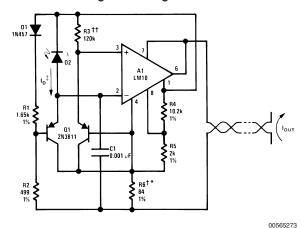
$$\begin{array}{l} 1 \text{ mA} \! \leq \! I_{OUT} \! \leq \! 5 \text{ mA} \\ \\ 0.01 \! \leq \! \frac{I_{D2}}{I_{D1}} \! \leq \! 100 \end{array}$$

Thermocouple Transmitter



 $200^{\circ}\text{C} \le \text{T}_p \le 700^{\circ}\text{C}$ 1 mA $\le \text{I}_{OUT} \le \text{5}$ mA †Gain Trim

Logarithmic Light Sensor



1 mA≤l_{OUT}≤5 mA

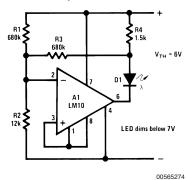
‡50 μA≤I_D≤500 μA

††Center Scale Trim

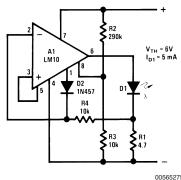
†Scale Factor Trim

*Copper Wire Wound

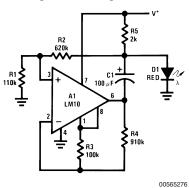
Battery-level Indicator



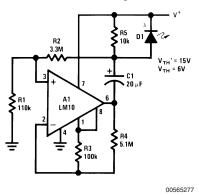
Battery-threshold Indicator



Single-cell Voltage Monitor



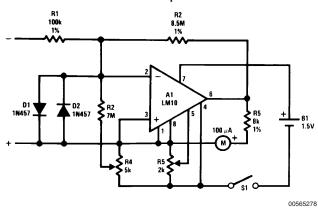
Double-ended Voltage Monitor



Flashes Above 1.2V Rate Increases With Voltage

Flash Rate Increases Above 6V and Below 15V

Meter Amplifier

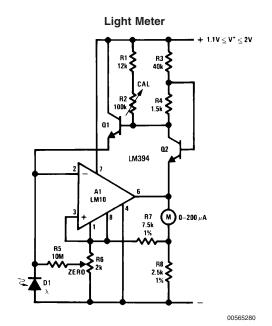


INPUT 10 mV, 100nA FULL-SCALE

Thermometer V* > 1V A1 LM10 R1 732 R2 1% R4 1.5k 1% 00565279

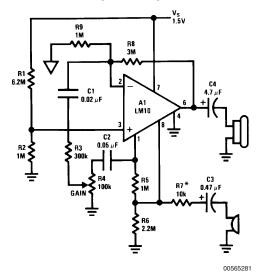
*Trim For Span

†Trim For Zero



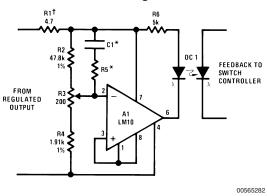
 $1{\le}\lambda/\lambda_0{\le}10^5$

Microphone Amplifier



 $\rm Z_{OUT}\text{-}680\Omega$ @ 5 kHz $\rm A_{V} \!\!\leq\! 1k$ $\rm f_1 \!\!\sim\! 100$ Hz $\rm f_2 \!\!-\! 5$ kHz $\rm R_L \!\!\sim\! 500$ *Max Gain Trim

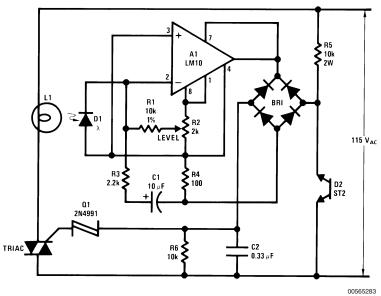
Isolated Voltage Sensor



†Controls "Loop Gain"

*Optional Frequency Shaping

Light-level Controller

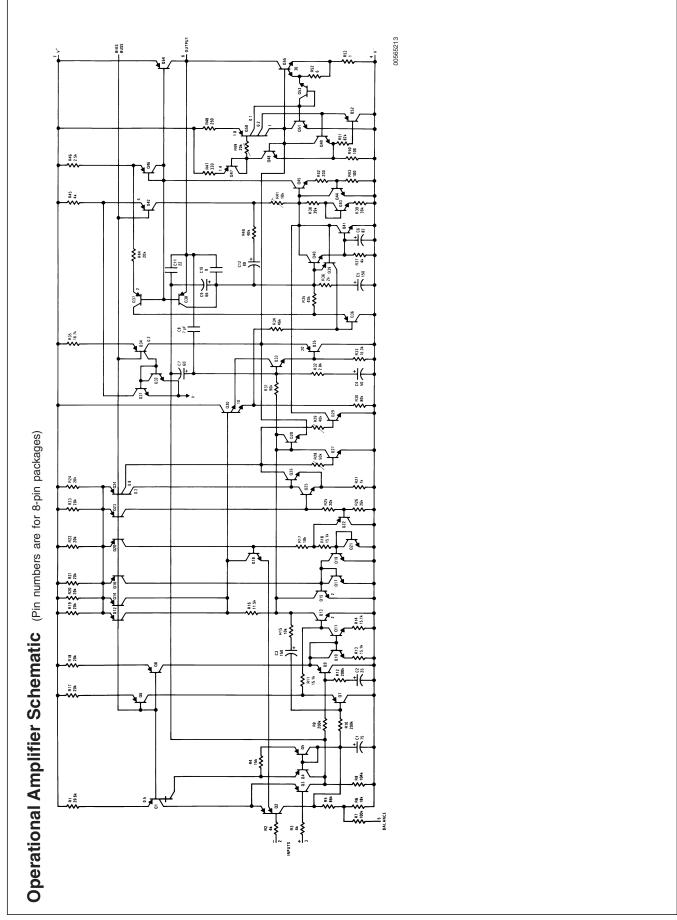


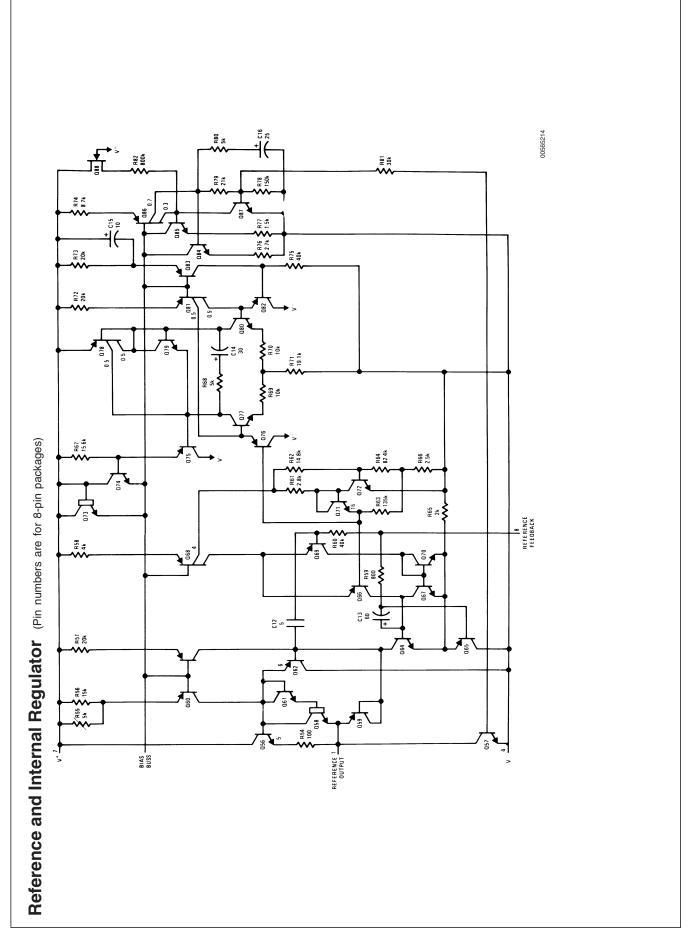
Note 10: Circuit descriptions available in application note AN-211.

Application Hints

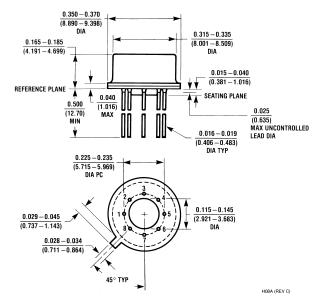
With heavy amplifier loading to V⁻, resistance drops in the V⁻ lead can adversely affect reference regulation. Lead resistance can approach 1Ω . Therefore, the common to the

reference circuitry should be connected as close as possible to the package.

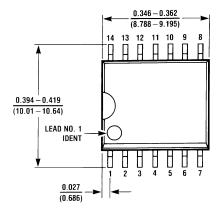


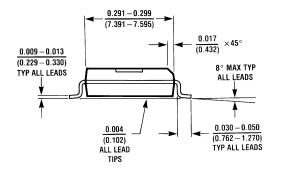


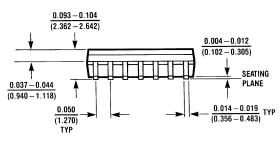
Physical Dimensions inches (millimeters) unless otherwise noted



Metal Can Package (H)
Order Number LM10BH, LM10CH, LM10CLH or LM10H/883
NS Package Number H08A



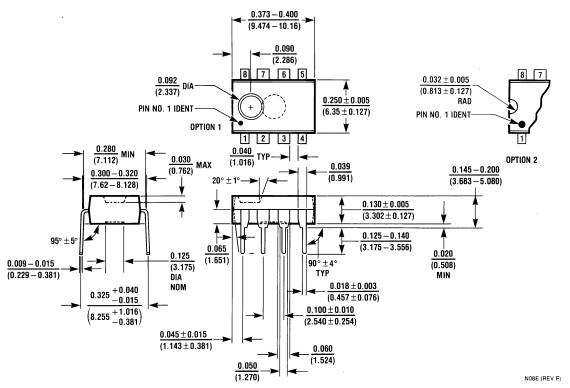




M14B (REV D)

S.O. Package (WM)
Order Number LM10CWM or LM10CWMX
NS Package Number M14B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Dual-In-Line Package (N) Order Number LM10CN or LM10CLN **NS Package Number N08E**

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